

12500 TI Boulevard, MS 8640, Dallas, Texas 75243

PCN#20211123000.2 Qualification of a new BOM for select devices in the SOIC package

Change Notification / Sample Request

Date: December 28, 2021

To: TOKYO ELECTRON DEVICE (DSTR) PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

Texas Instruments requires acknowledgement of receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If additional data is required, requests must be received within **30** days of this notification.

The changes discussed within this PCN will not take effect any earlier than the proposed first ship date on Page 3 of this notification, unless customer agreement has been reached on an earlier implementation of the change.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice or to provide acknowledgement of this PCN, you may contact your local Field Sales Representative or the PCN Team (PCN_www_admin_team@list.ti.com). For sample requests or sample related questions, contact your local Field Sales Representative.

Sincerely,

PCN Team SC Business Services

20211123000.2 Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past sixty (60) months. The corresponding customer part number is also listed, if available.

DEVICE	CUSTOMER PART NUMBER
SN65HVD1050AQDRQ1	null
SN65HVDA1040AQDRQ1	null
SN65HVDA1050AQDRQ1	null
SN65HVD1050QDRQ1	null

Technical details of this Product Change follow on the next page(s).

PCN Nu	mber:	20211123	3000.2					PCN D	ate:	December 2021	28,
Title:	Qualifica	ation of a n	ew BOM	1 fo	r select	devices in the SOIC	pac	kage		-	
Custom	er Conta	ct: PCN A	Manager		Dept:	Quality Services					
Propose	ed 1 st Shi	ip Date:	June	28	2022	Estimated Ava		mple ility:		provided at ole request	
Change	Type:										
	embly Site				Design				r Bum		
	Assembly Process Assembly Materials					Data Sheet Wafer Bump Material					
	•	terials pecification			Test Si	ımber change	$\frac{\square}{\square}$		r Bum r Fab S	p Process	
				\vdash	Test Pr		$\frac{\sqcup}{\sqcap}$			Materials	
ПППС	Packing/Shipping/Labeling				103011	00033				Process	
					PCN	l Details					
Descrip	tion of C	hange:									
	This PCN is to inform of the qualification of a new BOM for the devices in the product affected section as follows:										
	V	Vhat				Current			Nev	W	
	Mount (Compound				4042500			4147	'858	
Mold Compound											
	Mold C	ompound				4205694			4211	.880	
		ompound ame Prep			Non	4205694 n-Roughened		R	4211 lough		
Reason		ame Prep			Non			R			
	Leadfr	ame Prep			Nor			R			
Continuit	Leadfroity of supp	ame Prep	m, Fit,	Fu			ity		lough	ened	
Continuit	Leadfroity of supp	ame Prep	m, Fit,	Fu		n-Roughened	ity		lough	ened	
Continuit Anticipa None	Leadfra for Chan ty of supp	ame Prep				n-Roughened	ity		lough	ened	
Anticipa None Impact Checked	Leadfra for Chan ty of supported imported on Envir	ame Prepage: oly act on For conmental	Rating status of	s f er	nction,	n-Roughened	ıg in	(posit	ive /	negative):	ngs.
Anticipa None Impact Checked change.	Leadfra for Chan ty of supported imported on Envir boxes inc If below to	ame Prepage: oly act on For onmental dicate the spoxes are compage:	Rating status of hecked,	s f er , th	nction, nvironme ere are	Quality or Reliabilental ratings following to the as	ig in	(posit	ive /	negative): n of this nmental ratio	ngs.
Anticipa None Impact Checked change.	ty of supported imparts on Environments boxes included imparts the content of the	ame Prepage: oly act on For conmental	Rating status of hecked,	s f er , th	nction, nvironme ere are	Quality or Reliabilental ratings following to the as	ig in	(posit	ive /	negative): n of this nmental ratio	ngs.
Anticipa None Impact Checked change.	ty of supported imported impor	ame Prepage: oly act on For onmental dicate the sooxes are co	Rating status of hecked, RI No Cha	f er, the	nction, nvironme ere are CH	Quality or Reliabilental ratings following no changes to the asset of	ig in	(posit	ive /	negative): n of this nmental ratio	ngs.
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Anticipa None Impact Checked change. No Changes	ty of supported imported impor	ame Prepage: oly act on For conmental dicate the spoxes are convex are convex.	Rating status of hecked, RI No Cha	f er, the	nction, nvironme ere are CH	Quality or Reliabilental ratings following no changes to the asset of	ig in	(posit	ive /	negative): n of this nmental ratio	ngs.
Anticipa None Impact Checked change. No Changes	Leadfra for Chan ty of supported imported import	ame Prepage: oly act on For onmental dicate the sooxes are co	Rating status of hecked, RI No Cha	f er , the ang	nction, nvironmeere are CH le	Quality or Reliabilental ratings following no changes to the asset of	g ir	npleme	entatio environ IEC No Ch	negative): n of this nmental ratio	ngs.
Anticipa None Impact Checked change. No Changes None Product	Leadfra for Chan ty of supported imparent on Envir boxes income to the second to the s	ame Prepage: oly act on For conmental dicate the sooxes are convex are convex are convex are convex.	Rating status of hecked, RI No Cha	f er, the EAC ang	nction, nvironme ere are CH le esulting	Quality or Reliabil ental ratings following the assemble of the assemble of the property of th	ng irr	npleme iated e	entatio enviror IEC No Ch	negative): n of this negative c 62474 ange	ngs.



Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

SOIC/SOP/SSOP Automotive UBOM Enterprise Qualification in TITL Approved 03-Dec-2018

Product Attributes

Attributes	Qual Device: LT1014DMDW	Qual Device: SN0302035DWRG4	Qual Device: TPIC6A595DWR
Automotive Grade Level	-	Grade 1	Grade 1
Operating Temp Range	-55 to +125 C	-40 to +125 C	-40 to +125 C
Product Function	Signal Chain	Signal Chain	Power Management
Wafer Fab Supplier	SFAB	DFAB	DFAB
Die Revision	J	С	С
Assembly Site	TAI	TAI	TAI
Package Type	SOIC	SOIC	SOIC
Package Designator	DW	DW	DW
Ball/Lead Count	16	20	24

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: LT1014DMDW	Qual Device: SN0302035DWRG4	Qual Device: TPIC6A595DWR
			ıp A – Acce	lerated En	vironment Stress Tests				
PC	A1	JEDEC J-STD-020 JESD22-A113	3	77	Automotive Preconditioning	Level 1-260C	No Fails	-	No Fails
PC	A1	JEDEC J-STD-020 JESD22-A113	3	77	Automotive Preconditioning	Level 3-260C	-	No Fails	-
AC	A3	JEDEC JESD22-A102	3	77	Autoclave 121C	96 Hours	2/154/0	3/231/0	3/231/0
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, -55/125C	1000 Cycles	2/153/0 (1)	-	-
тс	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, -55/150C	1000 Cycles	-	3/228/0 (2)	3/231/0
TC- BP	A4	MIL-STD883 Method 2011	1	30	Post TC Bond Pull	Wires	2/60/0	3/90/0	3/90/0
PTC	A5	JEDEC JESD22-A105	1	45	Power Temperature Cycle	1000 Cycles	N/A	N/A	N/A
HTSL	. A6	JEDEC JESD22-A103	1	45	High Temp Storage Bake 150C	1000 Hours	2/90/0	-	-
HTSL	. A6	JEDEC JESD22-A103	1	45	High Temp Storage Bake 175C	500 Hours	-	3/135/0	3/135/0
		Test Grou	ıp B – Acce	lerated Li	fetime Simulation Tests				
EDR	ВЗ	AEC Q100-005	3	77	NVM Endurance, Data Retention, and Operational Life	-	N/A	N/A	N/A
		Test Gr	oup C – Pac	ckage Ass	embly Integrity Tests				
WBS	C1	AEC Q100-001	1	30	Wire Bond Shear (Cpk>1.67)	Wires	2/60/0	3/90/0	3/90/0
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull (Cpk>1.67)	Wires	2/60/0	3/90/0	3/90/0
SD	C3	JEDEC JESD22-B102	1	15	Solderability	>95% Lead Coverage	2/30/0	3/45/0	3/45/0
PD	C4	JEDEC JESD22-B100 and B108	3	10	Physical Dimensions (Cpk>1.67)	-	2/20/0	3/30/0	3/30/0
LI	C6	JEDEC JESD22-B105	1	50	Lead Integrity	-	-	-	-

⁻ QBS: Qual By Similarity
- Qual Devices qualified at LEVEL1-260CG: LT1014DMDW and TPIC6A595DWR
- Qual Device qualified at LEVEL3-260CG: SN0302035DWRG4
- Device LT1014DMDW contains multiple dies.

		Test Group D – Die Fabrication Reliability Tests								
Г	EM	D1	JESD61		_	Electromigration		Completed Per Process	Completed Per Process	Completed Per Process
	LIVI	ויט	JESDOT	-	-	Liectioniigiation	-	Technology Requirements	Technology Requirements	Technology Requirements
	TDDB	D2	JESD35			Time Dependant Dielectric		Completed Per Process	Completed Per Process	Completed Per Process
	IDDB	D2	JESUSS	-	-	Breakdown	-	Technology Requirements	Technology Requirements	Technology Requirements
Г	HCI	D3	JESD60 &			Hot Injection Carrier		Completed Per Process	Completed Per Process	Completed Per Process
	1101	D3	28	-	-	not injection carrier	-	Technology Requirements	Technology Requirements	Technology Requirements
Г	NBTI	D4				Negative Bias Temperature		Completed Per Process	Completed Per Process	Completed Per Process
	INDII	D4	_	-	-	Instability	-	Technology Requirements	Technology Requirements	Technology Requirements
	SM	D5			_	Stress Migration		Completed Per Process	Completed Per Process	Completed Per Process
L	Sivi	Do			_	Stress Wilgiation	_	Technology Requirements	Technology Requirements	Technology Requirements

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C Grade 1 (or Q): -40°C to +125°C Grade 2 (or T): -40°C to +105°C Grade 3 (or I): -40°C to +85°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold: HTOL, ED Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

Note (1): 1 unit was missing/lost before test. Note (2): 3 units were missing/lost before test.

TI Qualification ID: 20180507-125733



TI Information Selective Disclosure

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Enterprise Qualification (Automotive) - SOIC Gen 2 Hyde D with Consolidated Leadframe Approved 13-Sep-2021

Product Attributes

Attributes	Qual Device: CD4093BQM96Q1	Qual Device: K3HVD1781QDRQ1	Qual Device: <u>SE555DR</u>	Qual Device: SN103592DR	Qual Device: SN74HC S08QDRQ1	Qual Device: TCAN1043GDRQ1	Qual Device: TCAN1044VDRQ1	Qual Device: TLC5916QDRQ1	Qual Device: TMS3705DDRQ1
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 3
Operating Temp Range	-40 to +125 C	-40 to +125 C	-55 to +125 C	-40 to +125 C	-40 to +125 C	-55 to +125 C	-40 to +125 C	-40 to +125 C	-40 to +85 C
Product Function	Signal Chain	Signal Chain	Signal Chain	Power Management	Signal Chain	Signal Chain	Signal Chain	Power Management	Logic
Wafer Fab Supplier	SH-BIP-1	DP1DM5	SH-BIP-1	SH-BIP-1	RFAB	MH8	RFAB	MH8	DL-LIN
Die Revision	-	-	В	С	B0	С	PG2.0	-	С
Assembly Site	FMX	MLA	TAI	TAI	MLA	FMX	MLA	FMX	TAI
Package Type	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC
Package Designator	D	D	D	D	D	D	D	D	D
Ball/Lead Count	14	8	8	8	14	14	8	16	16

- QBS: Qual By Similarity
- Qual Devices CD4093BOM96Q1, K3HVD1781QDRQ1, SE555DR, SN103592DR, SN74HCS08QDRQ1, TCAN1043GDRQ1, TCAN1044VDRQ1_TLC5916QDRQ1 are qualified at LEVEL1-260CG Qual Device TMS3705DDRQ1 is qualified at LEVEL3-260CG

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

	Typ e	#	Test Spec	Mi n L ot Qt y	SS/L ot	Test Name / Condition	Durati on	Qual Device: CD4093BQ M96Q1	Qual Device: <u>K3HVD1781Q</u> DRQ1	Qual Device: <u>SE555DR</u>	Qual Device: SN103592 DR	Qual Device: SN74HCS08Q DRQ1	Qual Device: TCAN1043G DRQ1	Qual Device: TCAN1044V DRQ1	Qual Device: TLC5916Q DRQ1	Qual Device: TMS3705D DRQ1
Te	st Gr	oup /		lerate	d Envir	onment Stres	s Tests									
	AC	A 3	JEDE C JESD 22- A102	3	77	Autoclave 121C	96 Hours	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0
	TC	A 4	JEDE C JESD 22- A104 and Appen dix 3	3	77	Temperatu re Cycle, - 65/150C	500 Cycle s	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0
	PT C	A 5	JEDE C JESD 22- A105	1	45	Power Temperatu re Cycle	1000 Cycle s	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
Τe	est Gr	oup	B – Acce	lerate	d Lifeti	me Simulatio	n Tests									
	ED R	B 3	AEC Q100- 005	3	77	NVM Endurance , Data Retention, and Operationa I Life	1	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
	Test (Grou		ckage	Assem	bly Integrity	Tests									
	WB S	C 1	AEC Q100- 001	1	30	Wire Bond Shear (Cpk>1.67)	i	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0
	WB P	C 2	MIL- STD8 83 Metho	1	30	Wire Bond Pull (Cpk>1.67)	-	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0

Typ e	#	Test Spec	Mi n L ot Qt y	SS/L ot	Test Name / Condition	Durati on	Qual Device: CD4093BQ M96Q1	Qual Device: <u>K3HVD1781Q</u> DRQ1	Qual Device: <u>SE555DR</u>	Qual Device: SN103592 DR	Qual Device: SN74HC S08Q DRQ1	Qual Device: TCAN1043G DRQ1	Qual Device: TCAN1044V DRQ1	Qual Device: TLC5916Q DRQ1	Qual Device: TMS3705D DRQ1
		d 2011													
SD	C 3	JEDE C JESD 22- B102	1	15	Surface Mount Solderabilit y >95% Lead Coverage	PB- Free Solder	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0
PD	C 4	JEDE C JESD 22- B100 and B108	3	10	Physical Dimension s (Cpk>1.67)	-	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0
SB S	C 5	AEC Q100- 010	3	50	Solder Ball Shear (Cpk>1.67)	Solder Balls	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
Ц	C 6	JEDE C JESD 22- B105	1	50	Lead Fatigue	Leads	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0
Ц	C 6	JEDE C JESD 22- B105	1	50	Lead Pull	Leads	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0
Test	Gro	up D – Di	e Fab	ricatior	Reliability To	ests									
EM	D 1	JESD 61	1	-	Electromigr ation	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents
TD DB	D 2	JESD 35	-	-	Time Dependant Dielectric Breakdown	-	Completed Per Process Technology	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy	Complete d Per Process Technolo gy	Completed Per Process Technology Requirement s	Completed Per Process Technology	Completed Per Process Technology	Complete d Per Process Technolog y	Completed Per Process Technolog y

Typ e	#	Test Spec	Mi n L ot Qt y	SS/L ot	Test Name / Condition	Durati on	Qual Device: <u>CD4093BQ</u> <u>M96Q1</u>	Qual Device: <u>K3HVD1781Q</u> <u>DRQ1</u>	Qual Device: <u>SE555DR</u>	Qual Device: <u>SN103592</u> <u>DR</u>	Qual Device: SN74HC S08Q DRQ1	Qual Device: <u>TCAN1043G</u> <u>DRQ1</u>	Qual Device: <u>TCAN1044V</u> <u>DRQ1</u>	Qual Device: TLC5916Q DRQ1	Qual Device: TMS3705D DRQ1
							Requireme nts		Requirem ents	Requirem ents		Requireme nts	Requireme nts	Requirem ents	Requirem ents
HCI	D 3	JESD 60 & 28	1	ı	Hot Injection Carrier	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents
NB TI	D 4	1	1	1	Negative Bias Temperatu re Instability	1	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents
SM	D 5	-	-	-	Stress Migration	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C Grade 1 (or Q): -40°C to +125°C Grade 2 (or T): -40°C to +105°C Grade 3 (or I): -40°C to +85°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20201023-136790

For questions regarding this notice, e-mails can be sent to the contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
WW PCN Team	PCN_ww_admin_team@list.ti.com

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